

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









MBRF120150 thru MBRF120200R

Silicon Power Schottky Diode

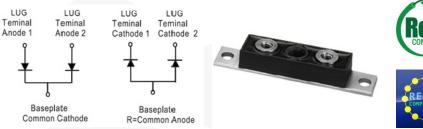
 $V_{RRM} = 150 V - 200 V$

 $I_{F(AV)} = 120 A$

Features

- High Surge Capability
- \bullet Types from 150 V to 200 V V_{RRM}
- · Not ESD Sensitive

TO-244AB Package







Maximum ratings, at T_i = 25 °C, unless otherwise specified ("R" devices have leads reversed)

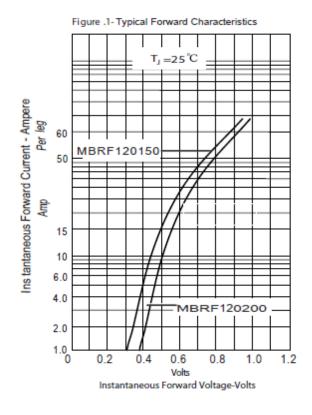
Parameter	Symbol	Conditions	MBRF120150(R)		MBRF120200(R)	Unit
Repetitive peak reverse voltage	V_{RRM}		150		200	V
RMS reverse voltage	V_{RMS}		106		141	V
DC blocking voltage	V_{DC}		150		200	V
Operating temperature	T _j		-55 to 150		-55 to 150	°C
Storage temperature	T_{stg}		-55 to 150	4	-55 to 150	°C

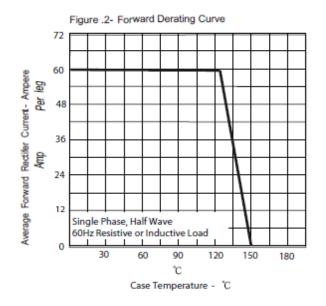
Electrical characteristics, at Tj = 25 °C, unless otherwise specified

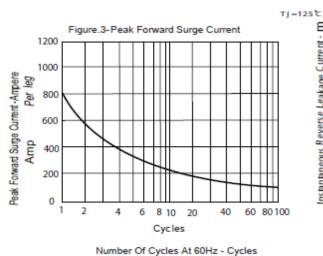
Symbol	Conditions	MBRF120150(R)	MBRF120200(R)	Unit
I _{F(AV)}	T _C = 125 °C	120	120	А
I _{FSM}	t _p = 8.3 ms, half sine	800	800	А
V_{F}	I _{FM} = 60 A, T _j = 25 °C	0.88	0.92	V
	T _j = 25 °C	1	1	
I_R	$T_j = 100 ^{\circ}C$	10	10	mA
	T _j = 150 °C	30	30	
s				
$R_{\Theta JC}$		0.80	0.80	°C/W
	I _{F(AV)} I _{FSM} V _F I _R	$I_{F(AV)} \qquad \qquad T_{C} = 125 ^{\circ}\text{C}$ $I_{FSM} \qquad \qquad t_{p} = 8.3 \text{ms, half sine}$ $V_{F} \qquad \qquad I_{FM} = 60 \text{A, } T_{j} = 25 ^{\circ}\text{C}$ $T_{j} = 25 ^{\circ}\text{C}$ $T_{j} = 100 ^{\circ}\text{C}$ $T_{j} = 150 ^{\circ}\text{C}$	$I_{F(AV)} \qquad T_C = 125 ^{\circ}C \qquad \qquad 120$ $I_{FSM} \qquad t_p = 8.3 \text{ms, half sine} \qquad \qquad 800$ $V_F \qquad I_{FM} = 60 \text{A, } T_j = 25 ^{\circ}C \qquad \qquad 0.88$ $T_j = 25 ^{\circ}C \qquad \qquad 1$ $I_R \qquad T_j = 100 ^{\circ}C \qquad \qquad 10$ $T_j = 150 ^{\circ}C \qquad \qquad 30$	$I_{F(AV)} \qquad T_C = 125 ^{\circ}C \qquad 120 \qquad 120$ $I_{FSM} \qquad t_p = 8.3 \text{ms, half sine} \qquad 800 \qquad 800$ $V_F \qquad I_{FM} = 60 \text{A, } T_j = 25 ^{\circ}C \qquad 0.88 \qquad 0.92$ $T_j = 25 ^{\circ}C \qquad 1 \qquad 1$ $I_R \qquad T_j = 100 ^{\circ}C \qquad 10 \qquad 10$ $T_j = 150 ^{\circ}C \qquad 30 \qquad 30$

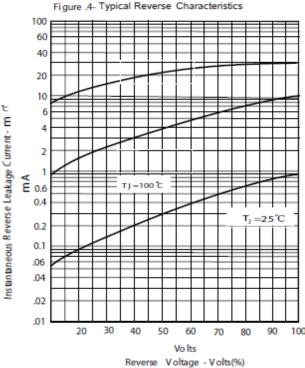


MBRF120150 thru MBRF120200R





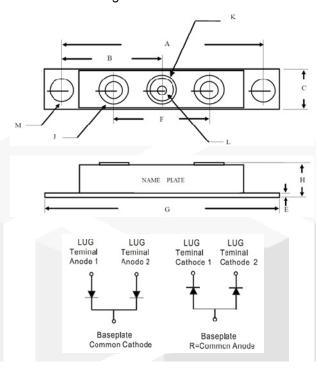




MBRF120150 thru MBRF120200R

Package dimensions and terminal configuration

Product is marked with part number and terminal configuration.



DIM	Inc	hes	Millimeters				
	Min	Max	Min	Max			
A	3.144	NOM	79.85	NOM			
В	1.565	1.585	39.75	40.26			
С	0.700	0.800	17.78	20.32			
Е	0.119	0.14	3.02	3.50			
F	1.358	REF.	34.50	REF.			
G	3.55	3.65	90.17	92.71			
Н	0.604	0.65	15.35	16.51			
J	1/4-20 UNC FULL						
K	0.380	0.410	9.65	10.41			
L	0.185	0.195	4.70	4.95			
M	0.275	0.295	6.99	7.49			